# JFET - VHF/UHF Amplifier Transistor

# **N-Channel**

### **Features**

• Pb-Free Packages are Available

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Drain-Source Voltage	V <sub>DS</sub>	25	Vdc
Gate-Source Voltage	V <sub>GS</sub>	25	Vdc
Gate Current	I <sub>G</sub>	10	mAdc

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

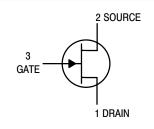
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1.  $FR-5 = 1.0 \times 0.75 \times 0.062$  in.



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SOT-23 (TO-236) CASE 318 STYLE 10

#### **MARKING DIAGRAM**



6x = Device Code

x = U for MMBFJ309LT1

x = T for MMBFJ310LT1

M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location)
\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
MMBFJ309LT1	SOT-23	3,000 / Tape & Reel
MMBFJ309LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBFJ310LT1	SOT-23	3,000 / Tape & Reel
MMBFJ310LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	1	•		•	1
Gate–Source Breakdown Voltage $(I_G = -1.0 \mu Adc, V_{DS} = 0)$	V <sub>(BR)GSS</sub>	-25	_	_	Vdc
Gate Reverse Current ( $V_{GS} = -15 \text{ Vdc}$ ) ( $V_{GS} = -15 \text{ Vdc}$ , $T_A = 125^{\circ}\text{C}$ )	I <sub>GSS</sub>		- -	-1.0 -1.0	nAdc μAdc
	G3(011)	-1.0 -2.0	_ _	-4.0 -6.5	Vdc
ON CHARACTERISTICS					
	D00	12 24	_ _	30 60	mAdc
Gate-Source Forward Voltage (I <sub>G</sub> = 1.0 mAdc, V <sub>DS</sub> = 0)	V <sub>GS(f)</sub>	-	-	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS		•	•		-
Forward Transfer Admittance (V <sub>DS</sub> = 10 Vdc, I <sub>D</sub> = 10 mAdc, f = 1.0 kHz)	Y <sub>fs</sub>	8.0	_	18	mmhos
Output Admittance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$	ly <sub>os</sub> l	-	-	250	μmhos
Input Capacitance $(V_{GS} = -10 \text{ Vdc}, V_{DS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$	C <sub>iss</sub>	-	-	5.0	pF
Reverse Transfer Capacitance (V <sub>GS</sub> = -10 Vdc, V <sub>DS</sub> = 0 Vdc, f = 1.0 MHz)	C <sub>rss</sub>	-	-	2.5	pF
Equivalent Short-Circuit Input Noise Voltage (V <sub>DS</sub> = 10 Vdc, I <sub>D</sub> = 10 mAdc, f = 100 Hz)	<del>e</del> n	-	10	_	nV/√ <del>Hz</del>

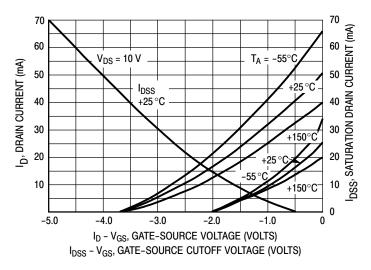


Figure 1. Drain Current and Transfer Characteristics versus Gate-Source Voltage

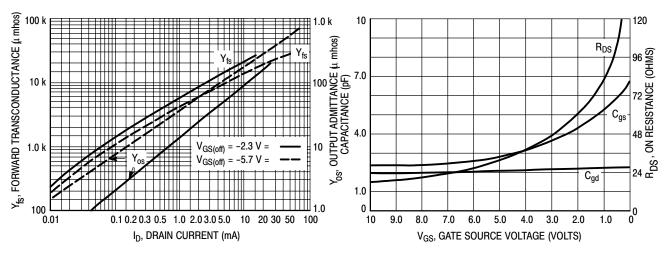


Figure 2. Common-Source Output Admittance and Forward Transconductance versus Drain Current

Figure 3. On Resistance and Junction Capacitance versus Gate-Source Voltage

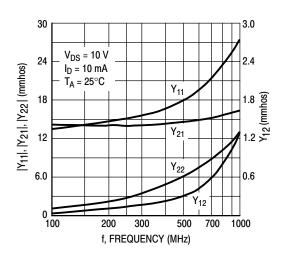


Figure 4. Common-Gate Y Parameter Magnitude versus Frequency

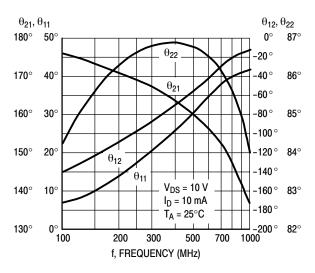


Figure 6. Common–Gate Y Parameter Phase–Angle versus Frequency

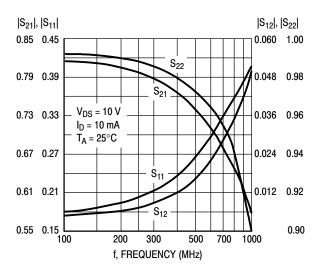


Figure 5. Common-Gate S Parameter Magnitude versus Frequency

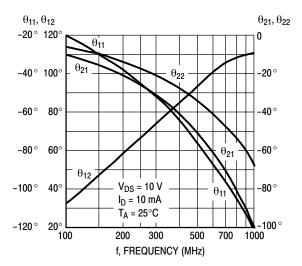
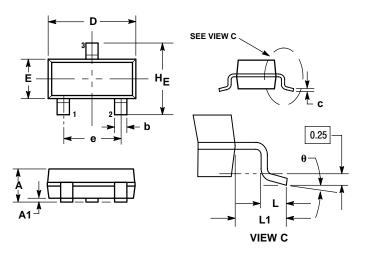


Figure 7. S Parameter Phase–Angle versus Frequency

## PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 ISSUE AN



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
   VALEM 1993
- Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

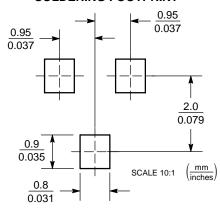
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

# STYLE 10:

PIN 1. DRAIN

- SOURCE
- 3. GATE

## **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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